



A Product Line of Diodes Incorporated



# FZT651

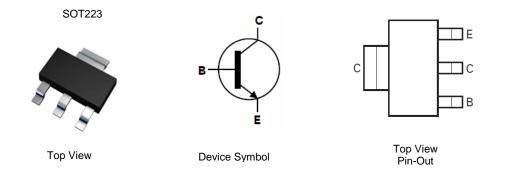
#### **60V NPN HIGH PERFORMANCE TRANSISTOR IN SOT223**

#### Features

- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 3A High Continuous Current
- I<sub>CM</sub> = 6A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 300mV @ 1A</li>
- Complementary PNP Type: FZT751
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



### Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT651TA	AEC-Q101	FZT651	7	12	1,000
FZT651TC	AEC-Q101	FZT651	13	12	4,000

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

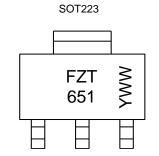
and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

Notes:



FZT 651 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)





# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	lc	3	A
Peak Pulse Current	I <sub>CM</sub>	6	A

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Dower Dissignation	(Note 5)	P	2	W
Power Dissipation	(Note 6)	PD	3	W
Thermal Desistance Junction to Ambient	(Note 5)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	12.9	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in steady-state.

6. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.

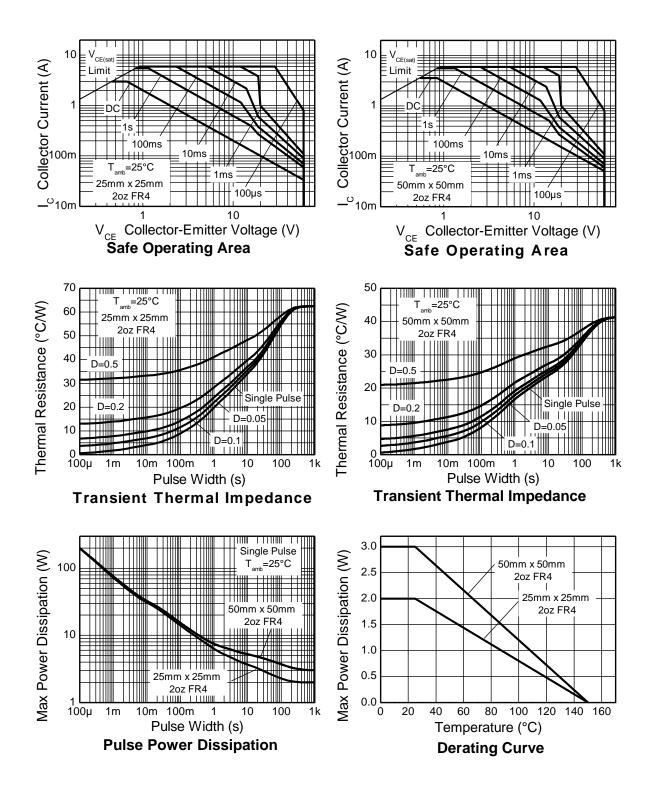
7. Thermal resistance from junction to solder-point (at the end of the collector lead).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





## Thermal Characteristics and Derating Information









# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

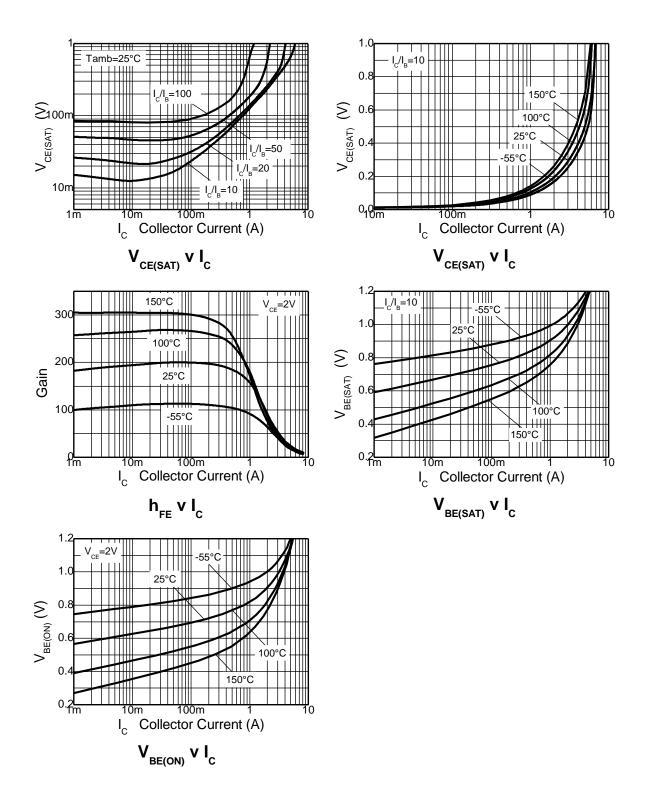
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	-	-	V	$I_{\rm C} = 100 \mu \rm A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	60	-	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	-	-	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current	I <sub>CBO</sub>	-	-	0.1		$V_{CB} = 60V$
Collector Cut-Oli Current		-	-	10	μA	V <sub>CB</sub> = 60V, T <sub>A</sub> = +125°C
Emitter Cut-Off Current	I <sub>EBO</sub>	-	-	100	nA	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	0.12	0.3	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Collector-Emitter Saturation Voltage (Note 9)		-	0.43	0.6	v	$I_{\rm C} = 3A, I_{\rm B} = 300 {\rm mA}$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	0.9	1.25	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	0.8	1.0	V	$I_C = 1A$ , $V_{CE} = 2V$
	hFE	70	200	-		$I_{C} = 50 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Coin (Note 0)		100	200	300		$I_{C} = 500 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Gain (Note 9)		80	170	-	_	$I_C = 1A$ , $V_{CE} = 2V$
		40	80	-		$I_C = 2A, V_{CE} = 2V$
Current Gain-Bandwidth Product (Note 9)	f <sub>T</sub>	140	175	-	MHz	$V_{CE} = 5V, I_C = 100mA, f = 100MHz$
Switching Timon	t <sub>on</sub>	-	45	-	20	$I_{C} = 500 \text{mA}, V_{CC} = 10 \text{V},$
Switching Times	t <sub>off</sub>	_	800	-	ns	$I_{B1} = I_{B2} = 50 \text{mA}$
Output Capacitance (Note 9)	C <sub>obo</sub>	-	-	30	pF	$V_{CB} = 10V$ , f = 1MHz

9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%. Note:





# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



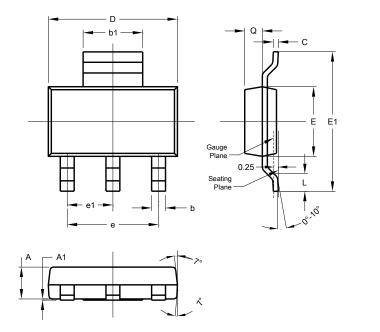






## **Package Outline Dimensions**

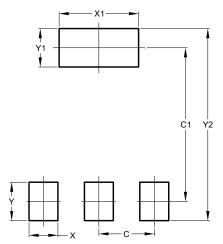
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
ш	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00





# **FZT651**

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